

ACTT8B-800C0 AC Thyristor Triac power switch 29 October 2013

Product data sheet

General description 1.

AC Thyristor Triac power switch in a SOT404 (D2PAK) surface mountable plastic package with self-protective clamping capabilities against low and high energy transients.

Features and benefits 2.

- Clamping structure ensuring safe high over-voltage withstand capability
- High minimum IGT for guaranteed immunity to gate noise •
- Full cycle AC conduction
- Over-voltage withstand capability to IEC 61000-4-5 •
- Pin compatible with standard triacs
- Planar passivated for voltage ruggedness and reliability
- Protective self turn-on capability for high energy transients
- Safe clamping capability for low energy over-voltage transients •
- Less sensitive gate for high noise immunity
- Surface mountable package •
- Triggering in three guadrants only
- Very high immunity to false turn-on by dV/dt

3. Applications

- AC fan, pump and compressor controls
- Highly inductive, resistive and safety loads
- Large and small appliances (White Goods)
- Reversing induction motor controls

Quick reference data 4.

Table 1. Qui	ck reference data					
Symbol	Parameter	Conditions	Min	Тур	Max	Unit
V _{DRM}	repetitive peak off- state voltage		-	-	800	V
I _{TSM}	non-repetitive peak on- state current	full sine wave; $T_{j(init)} = 25 \text{ °C};$ t _p = 20 ms; <u>Fig. 4</u> ; <u>Fig. 5</u>	-	-	80	A
Tj	junction temperature		-	-	125	°C
I _{T(RMS)}	RMS on-state current	full sine wave; T _{mb} ≤ 105 °C; <u>Fig. 1;</u> <u>Fig. 2; Fig. 3</u>	-	-	8	A





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Symbol	Parameter	Conditions	Min	Тур	Мах	Unit
V _{PP}	peak pulse voltage	T _j = 25 °C; non-repetitive, off-state; Fig. <u>6</u>	-	-	2	kV
Static chara	acteristics	· · ·		-		
I _{GT}	gate trigger current	V_D = 12 V; I _T = 100 mA; LD+ G+; T _j = 25 °C; <u>Fig. 8</u>	5	-	30	mA
		V_D = 12 V; I _T = 100 mA; LD+ G-; T _j = 25 °C; Fig. 8	5	-	30	mA
		V_D = 12 V; I _T = 100 mA; LD- G-; T _j = 25 °C; Fig. 8	5	-	30	mA
V _{CL}	clamping voltage	I _{CL} = 0.1 mA; t _p = 1 ms; T _j = 25 °C	850	-	-	V
Dynamic cl	narateristics	1				
dV _D /dt	rate of rise of off-state voltage	V_{DM} = 536 V; T _j = 125 °C; (V _{DM} = 67% of V _{DRM}); exponential waveform; gate open circuit	2000	-	-	V/µs
dI _{com} /dt	rate of change of commutating current	$V_{D} = 400 \text{ V}; \text{T}_{\text{j}} = 125 \text{ °C}; \text{I}_{\text{(RMS)}} = 8 \text{ A};$ $dV_{\text{com}}/dt = 20 \text{ V}/\mu\text{s}; \text{ (snubberless} \text{ condition}); \text{ gate open circuit}$	8	-	-	A/ms

5. Pinning information

Table 2.	Pinning	information		
Pin	Symbol	Description	Simplified outline	Graphic symbol
1	СМ	common	mb	LD
2	LD	load		G
3	G	gate		СМ
mb	LD	mounting base; load	D2PAK (SOT404)	003aaf296

6. Ordering information

Table 3. Ordering information							
Type number	Package						
	Name	Description	Version				
ACTT8B-800C0	D2PAK	plastic single-ended surface-mounted package (D2PAK); 3 leads (one lead cropped)	SOT404				

7. Marking

Table 4. Marking codes	
Type number	Marking code
ACTT8B-800C0	ACTT8B-800C0

8. Limiting values

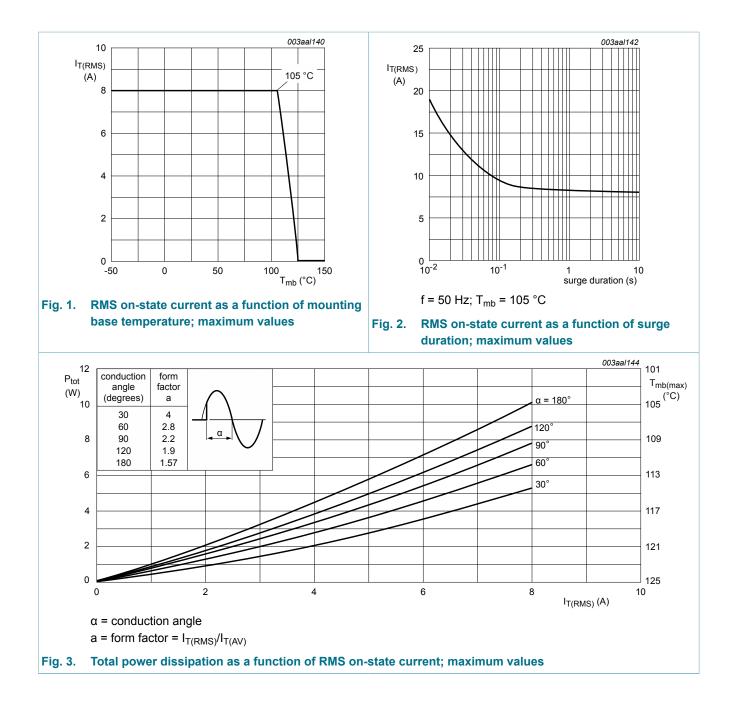
Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions	Min	Мах	Unit
V _{DRM}	repetitive peak off-state voltage		-	800	V
I _{T(RMS)}	RMS on-state current	full sine wave; T _{mb} ≤ 105 °C; <u>Fig. 1;</u> <u>Fig. 2; Fig. 3</u>	-	8	A
I _{TSM}	non-repetitive peak on-state current	full sine wave; T _{j(init)} = 25 °C; t _p = 20 ms; <u>Fig. 4</u> ; <u>Fig. 5</u>	-	80	A
		full sine wave; $T_{j(init)}$ = 25 °C; t_p = 16.7 ms	-	88	A
l ² t	I ² t for fusing	t _p = 10 ms; sine-wave pulse	-	32	A ² s
dI _T /dt	rate of rise of on-state current	I_T = 12 A; I_G = 0.2 A; dI_G/dt = 0.2 A/µs	-	100	A/µs
I _{GM}	peak gate current	t = 20 μs	-	2	А
P _{GM}	peak gate power		-	5	W
P _{G(AV)}	average gate power	over any 20 ms period	-	0.5	W
T _{stg}	storage temperature		-40	150	°C
Tj	junction temperature		-	125	°C
V _{PP}	peak pulse voltage	T _j = 25 °C; non-repetitive, off-state; Fig. 6	-	2	kV

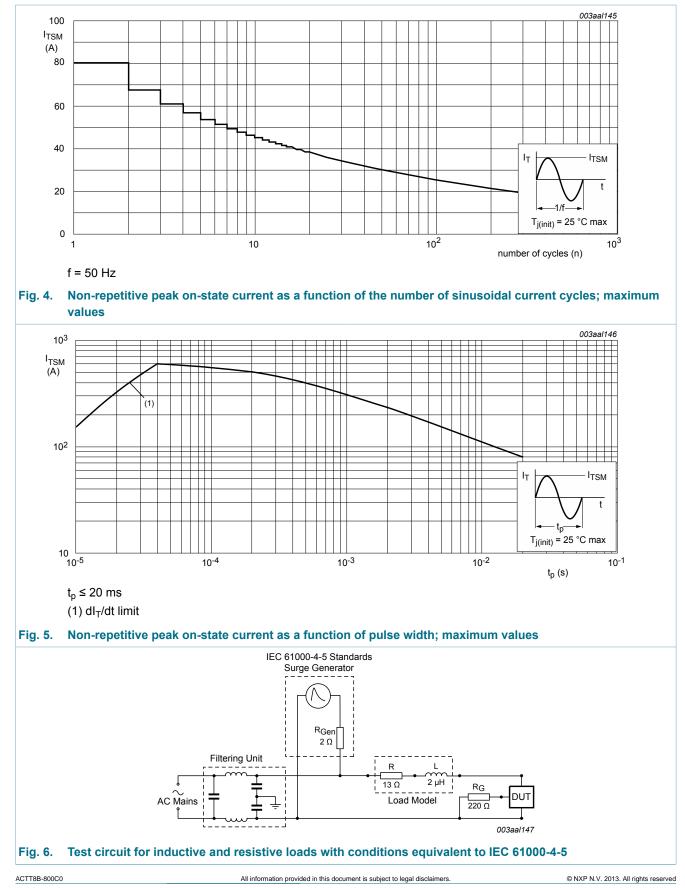
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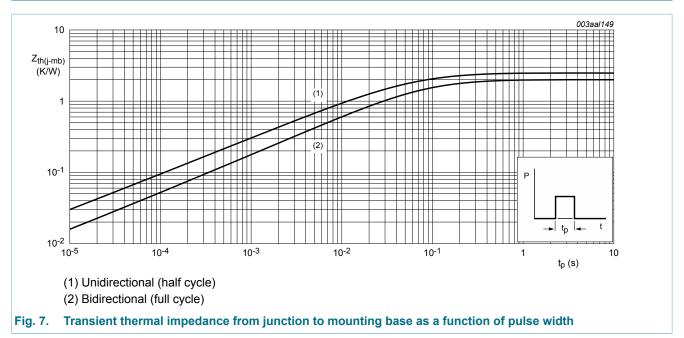
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9. Thermal characteristics

Table 6. The	rmal characteristics					
Symbol	Parameter	Conditions	Min	Тур	Max	Unit
R _{th(j-mb)}	thermal resistance	full cycle; Fig. 7	-	-	2	K/W
	from junction to mounting base	half cycle; <u>Fig. 7</u>	-	-	2.4	K/W
R _{th(j-a)}	thermal resistance from junction to ambient	in free air; printed circuit board (FR4) mounted	-	55	-	K/W



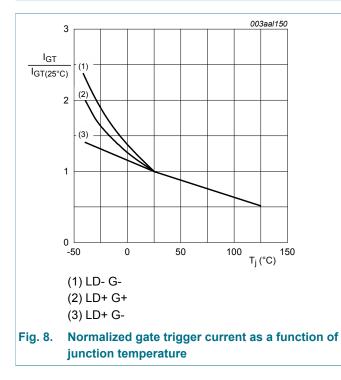
10. Characteristics

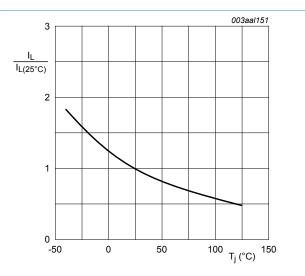
Table 7. Characteristics							
Symbol	Parameter	Conditions	Min	Тур	Max	Unit	
Static charac	Static characteristics						
I _{GT} gate	gate trigger current	$V_D = 12 \text{ V}; \text{ I}_T = 100 \text{ mA}; \text{ LD+ G+};$ T _j = 25 °C; <u>Fig. 8</u>	5	-	30	mA	
		V_D = 12 V; I _T = 100 mA; LD+ G-; T _j = 25 °C; <u>Fig. 8</u>	5	-	30	mA	
		V _D = 12 V; I _T = 100 mA; LD- G-; T _j = 25 °C; <u>Fig. 8</u>	5	-	30	mA	
IL	latching current	V _D = 12 V; I _G = 100 mA; LD+ G+; T _j = 25 °C; <u>Fig. 9</u>	-	-	50	mA	

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Symbol	Parameter	Conditions	Min	Тур	Max	Unit
		V_D = 12 V; I _G = 100 mA; LD+ G-; T _j = 25 °C; <u>Fig. 9</u>	-	-	70	mA
		V_D = 12 V; I _G = 100 mA; LD- G-; T _j = 25 °C; <u>Fig. 9</u>	-	-	50	mA
I _H	holding current	V _D = 12 V; T _j = 25 °C; <u>Fig. 10</u>	-	-	35	mA
V _T	on-state voltage	I _T = 10 A; T _j = 25 °C; <u>Fig. 11</u>	-	1.3	1.5	V
V _{GT} gate trigger voltag	gate trigger voltage	V _D = 12 V; I _T = 100 mA; T _j = 25 °C; Fig. 12	-	0.8	1	V
		V _D = 400 V; I _T = 100 mA; T _j = 125 °C; Fig. 12	0.2	0.45	-	V
I _D	off-state current	V _D = 800 V; T _j = 25 °C	-	-	10	μA
		V _D = 800 V; T _j = 125 °C	-	-	0.5	mA
V _{CL}	clamping voltage	I _{CL} = 0.1 mA; t _p = 1 ms; T _j = 25 °C	850	-	-	V
Dynamic ch	narateristics	l		1		
dV _D /dt	rate of rise of off-state voltage	V_{DM} = 536 V; T _j = 125 °C; (V _{DM} = 67% of V _{DRM}); exponential waveform; gate open circuit	2000	-	-	V/µs
dl _{com} /dt	rate of change of commutating current	V_D = 400 V; T_j = 125 °C; $I_{T(RMS)}$ = 8 A; dV _{com} /dt = 20 V/µs; (snubberless condition); gate open circuit	8	-	-	A/ms

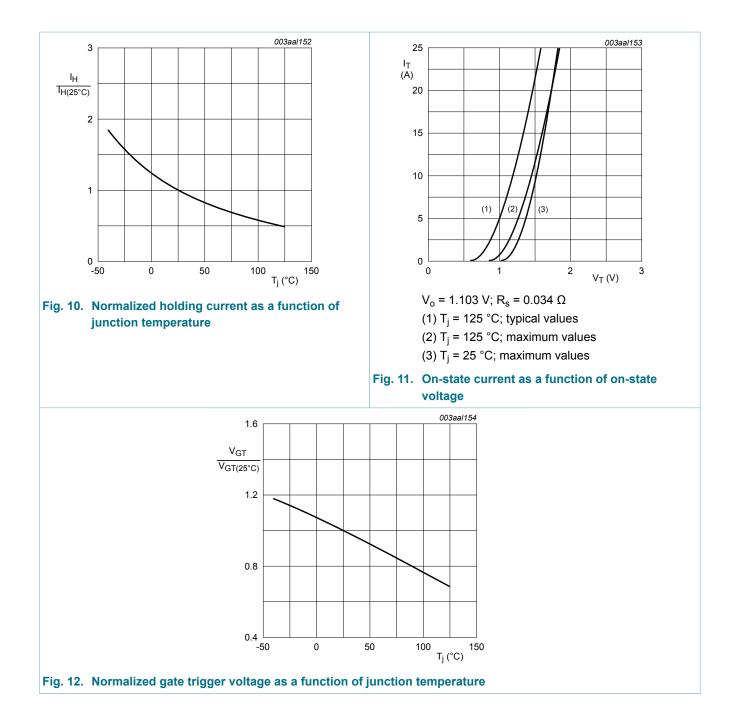






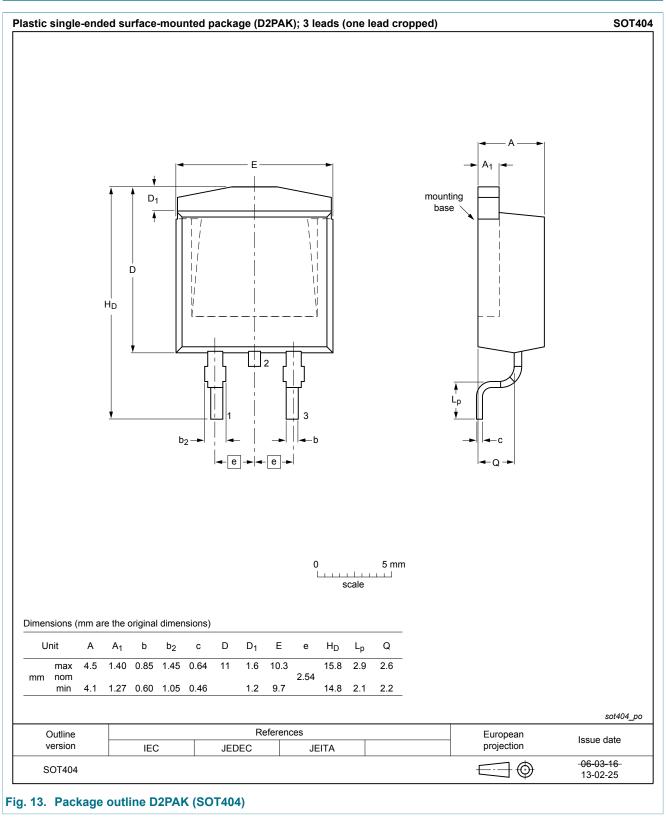
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11. Package outline

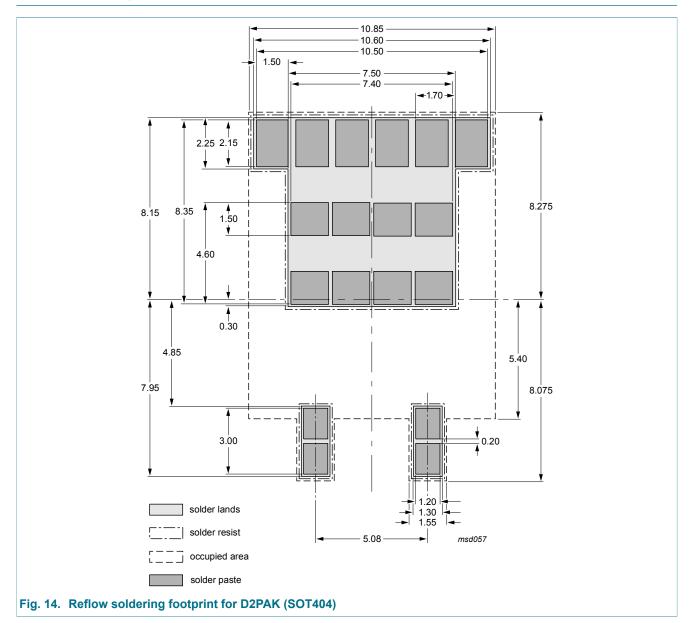


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12. Soldering



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13. Legal information

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Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
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	Features and benefits

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